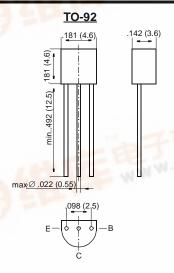
BF420, BF422

Small Signal Transistors (NPN)



Dimensions in inches and (millimeters)

WWW.DZSD

FEATURES

- NPN Silicon Epitaxial Planar Transistors especially suited for application in class-B video output stages of TV receivers and monitors.
- As complementary types, the PNP transistors BF421 and BF423 are recommended



MECHANICAL DATA

Case: TO-92 Plastic Package Weight: approx. 0.18 g

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

		Symbol	Value	Unit	
Collector-Base Voltage	BF420 BF422	V _{CBO}	300 250	V	
Collector-Emitter Voltage	BF422	V _{CEO}	250	V	
Collector-Emitter Voltage	BF420	V _{CER}	300	V	
Emitter-Base Voltage	SC.COM	V _{EBO}	5	V	
Collector Current		I _C	50	mA	
Pea <mark>k Collector Current</mark>		I _{CM}	100	mA	
Power Dissipation at T _{amb} = 25 °C		P _{tot}	830 ¹⁾	mW	
Junction Temperature		T _j	150	°C	
Storage Temperature Range		T _S	-65 to +150	°C	



BF420, BF422

ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified

	Symbol	Min.	Тур.	Max.	Unit
Collector-Base Breakdown Voltage at $I_C = 100 \mu A$, $I_B = 0$ BF420 BF422	V _(BR) CBO V _(BR) CBO	300 250			V
Collector-Emitter Breakdown Voltage BF422 at I _C = 10 mA, I _E = 0	V _{(BR)CEO}	250	_	_	V
Collector-Emitter Breakdown Voltage BF420 at R _{BE} = 2.7 k Ω , I _C = 10 mA	V _{(BR)CER}	300	_	_	V
Emitter-Base Breakdown Voltage at $I_E = 100 \mu A$, $I_B = 0$	V _{(BR)EBO}	5	-	_	V
Collector-Base Cutoff Current at $V_{CB} = 200 \text{ V}$, $I_E = 0$	I _{CBO}	_	_	10	nA
Collector-Emitter Cutoff Current at R _{BE} = 2.7 k Ω , V _{CE} = 250 V at R _{BE} = 2.7 k Ω , V _{CE} = 200 V, T _j = 150 °C	I _{CER}			50 10	nA μA
Collector Saturation Voltage at I _C = 30 mA, I _B = 5 mA	V _{CEsat}	_	_	0.6	V
DC Current Gain at $V_{CE} = 20 \text{ V, } I_{C} = 25 \text{ mA}$	h _{FE}	50	-	_	_
Gain-Bandwidth Product at $V_{CE} = 10 \text{ V}$, $I_{C} = 10 \text{ mA}$	f _T	60	_	_	MHz
Feedback Capacitance at $V_{CE} = 30 \text{ V}$, $I_{C} = 0$, $f = 1 \text{ MHz}$	C _{re}	_	_	1.6	pF
Thermal Resistance Junction to Ambient Air	R _{thJA}	_		150 ¹⁾	K/W

¹⁾ Valid provided that leads are kept at ambient temperature at a distance of 2 mm from case

